

UA78M 500mA, Positive-Voltage Linear Regulator

1 Features

- Input voltage range (V_{IN}): 5.3V to 30V
- Absolute maximum input voltage:
 - Legacy chip: 35V
 - New chip: 45V
- Fixed output voltage range (V_{OUT}): 3.3V to 12V
- Output current (I_{OUT}): Up to 500mA
- Quiescent current I_Q : 4.5mA
- Built-in, short-circuit current limiting and thermal protection
- Stable without any external components
- Operating junction temperature range:
 - Legacy chip C versions: 0°C to +125°C
 - Legacy chip I version: –40°C to +125°C
 - New chip: –40°C to +125°C

2 Applications

- [Onboard charging](#)
- [Washers and dryers](#)
- [Residential lighting](#)
- [Battery backup units \(BBU\)](#)
- [Air conditioner outdoor units](#)

3 Description

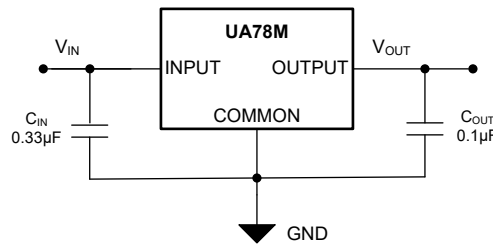
The UA78M fixed-voltage integrated-circuit voltage regulator is designed for a wide range of applications. Use the UA78M for on-card regulation to attenuate post regulation noise and distribution problems associated with single-point regulation. The UA78M delivers up to 500mA of output current. Additionally, the UA78M does not need external components for stable operation across the load current range. The internal current-limiting and thermal-shutdown features of this regulator help protect the device from overload.

The UA78M is characterized for the junction temperature range of –40°C to +125°C. Device performance for new and legacy chips is denoted throughout the document. See the [Device Nomenclature](#) table for more details.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
UA78M	DCY (SOT-223, 3)	6.5mm × 7mm
	KVU (TO-252, 3)	6.6mm × 10.11mm

- (1) For more information, see the [Mechanical, Packaging, and Orderable Information](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Schematic



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4 Pin Configuration and Functions

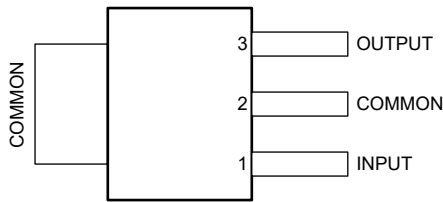


Figure 4-1. DCY Package, 3-Pin SOT-223 (Top View)

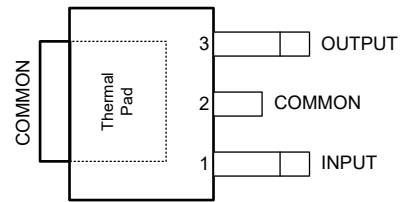


Figure 4-2. KVU Package, 3-Pin TO-252 (Top View)

Table 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
COMMON	2	—	Ground
INPUT	1	I	Input pin. Use the recommended capacitor value as listed in the Recommended Operating Conditions table. Place the input capacitor as close to the INPUT and COMMON pins of the device as possible.
OUTPUT	3	O	Output pin. Use the recommended capacitor value as listed in the Recommended Operating Conditions table. Place the output capacitor as close to the OUTPUT and COMMON pins of the device as possible.

5 Specifications

5.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Input voltage, V_I (for Legacy Chip)	UA78M33C, UA78M33I, UA78M05C, UA78M05I, UA78M06C, UA78M08C, UA78M09C, UA78M10C, UA78M12C		35	V
Input voltage, V_I (for New Chip)	UA78M33C, UA78M33I, UA78M05C, UA78M05I, UA78M09C, UA78M10C, UA78M12C		45	V
Output voltage, V_O (for New Chip)		-0.3	12	V
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	2500
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	2000

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	TYP	MAX	UNIT	
VIN	Input voltage	UA78M33C, UA78M33I (Legacy chip)	5.3		25	V
		UA78M33C, UA78M33I (New chip)	5.3		30	
		UA78M05C, UA78M05I (Legacy chip)	7		25	
		UA78M05C, UA78M05I (New chip)	7		30	
		UA78M06 (Legacy chip)	8		25	
		UA78M08 (Legacy chip)	10.5		25	
		UA78M09 (Legacy chip)	11.5		26	
		UA78M09 (New chip)	11.5		30	
		UA78M10 (Legacy chip)	12.5		28	
		UA78M10 (New chip)	12.5		30	
		UA78M12 (Legacy chip)	14.5		30	
		UA78M12 (New chip)	14.5		30	
C_{IN} ⁽²⁾	Input capacitor ⁽³⁾		0.33		μF	
C_{OUT} ⁽²⁾	Output capacitor ⁽⁴⁾		0.1	470	μF	
I_O	Output current			500	mA	
T_J	Operating junction temperature	UA78MxxC (Legacy chip)	0		125	°C
		UA78MxxI (Legacy chip)	-40		125	
		UA78MxxC, UA78MxxI (New chip)	-40		125	

(1) All voltages are with respect to GND.

(2) UA78M regulator does not need any external capacitors for LDO stability.

(3) An input capacitor with value of 0.33 μF is recommended to counteract the effect of source resistance and inductance, which can in some cases cause symptoms of system level instability such as ringing or oscillation, especially in the presence of load transients.

(4) An output capacitor with value of 0.1 μF is recommended to improve the load and line transient performance of the UA78M regulator. The maximum output capacitor is guaranteed by design

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		UA78Mxx	UA78Mxx	UA78Mxx	UA78Mxx	UA78Mxx	UNIT
		DCY (Legacy Chip)	DCY (New Chip)	KCS (Legacy Chip only)	KVU (Legacy chip)	KVU (New chip)	
		3 PINS	3 PINS	3 PINS	3 PINS	3 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	53	77.7	19	30.2	32.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	30.6	44.6	17	–	40	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	–	–	3	–	3.3	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.5 Electrical Characteristics: UA78M33 (Both Legacy and New Chip)

specified at T_J = 25°C, V_I = 8 V, C_{IN} = 0.33 μF, C_{OUT} = 0.1 μF, and I_O = 350 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT	
Output voltage	V _I = 8V to 20V, and I _O = 5mA to 350mA	Legacy chip and new chip	3.2	3.3	3.4	V	
		T _J = full range Legacy chip	3.1	3.3	3.5		
		T _J = –40°C to 125°C New chip	3.1	3.3	3.5		
Output voltage line regulation	I _O = 200mA, V _{IN} = 5.3V to 25V	Legacy chip		9	100	mV	
		New chip		28	50		
	I _O = 200mA, V _{IN} = 8V to 25V	Legacy chip		3	50		
		New chip		9	20		
Ripple rejection	V _I = 8V to 18V, f = 120Hz	I _O = 100mA, T _J = full range Legacy chip		62		dB	
		I _O = 100mA, T _J = –40°C to 125°C New chip		57			
		I _O = 300mA	Legacy chip	62	80		
			New chip	56	62		
Output voltage load regulation	V _I = 8V and I _O = 5mA to 500mA	Legacy chip		20	100	mV	
		New chip		20	40		
Temperature coefficient of output voltage	I _O = 5mA	T _J = full range Legacy chip		–1		mV/°C	
		T _J = –40°C to 125°C New chip		–1			
Output noise voltage	f = 10 Hz to 100 KHz	Legacy chip		40	200	μV _{rms}	
		New chip		80	200		
Dropout voltage		Legacy chip and new chip		2.0		V	
Bias current		Legacy chip		4.5	6	mA	
		New chip	3.5	4.5	6		
Bias current change	V _I = 8V to 25V, I _O = 200mA	T _J = full range Legacy chip			0.8	mA	
		T _J = –40°C to 125°C New chip			0.8		
	I _O = 5 mA to 350mA	T _J = full range Legacy chip			0.5		
		T _J = –40°C to 125°C New chip			0.5		
Short-circuit output current	V _I = 35V	Legacy chip		300		mA	
	V _I = 30V	New chip		400			
Peak output current		Legacy chip		700		mA	
		New chip		735			

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.6 Electrical Characteristics: UA78M05 (Both Legacy and New Chip)

specified at $T_J = 25^\circ\text{C}$, $V_I = 10\text{V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT	
Output voltage	$V_I = 7\text{V to }20\text{V}$, and $I_O = 5\text{mA to }350\text{mA}$	Legacy chip and new chip	4.8	5	5.2	V	
		$T_J = \text{full range}$ Legacy chip	4.75		5.25		
	$V_I = 7.2\text{V to }20\text{V}$, and $I_O = 5\text{mA to }350\text{mA}$	$T_J = -40^\circ\text{C to }125^\circ\text{C}$ New chip	4.75		5.25		
Output voltage line regulation	$I_O = 200\text{mA}$, $V_{IN} = 7\text{V to }25\text{V}$	Legacy chip		3	100	mV	
		New chip		13	30		
	$I_O = 200\text{mA}$, $V_{IN} = 8\text{V to }25\text{V}$	Legacy chip		1	50		
		New chip		13	30		
Ripple rejection	$V_I = 8\text{V to }18\text{V}$, $f = 120\text{Hz}$	$I_O = 100\text{mA}$, $T_J = \text{full range}$ Legacy chip	62			dB	
		$I_O = 100\text{mA}$, $T_J = -40^\circ\text{C to }125^\circ\text{C}$ New chip	56				
		$I_O = 300\text{mA}$	Legacy chip	62	80		
			New chip	52	58		
Output voltage load regulation	$I_O = 5\text{mA to }500\text{mA}$	Legacy chip		20	100	mV	
		New chip		25	60		
	$I_O = 5\text{mA to }200\text{mA}$	Legacy chip		10	50		
		New chip		5	20		
Temperature coefficient of output voltage	$I_O = 5\text{mA}$	$T_J = \text{full range}$ Legacy chip		-1		mV/ $^\circ\text{C}$	
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$ New chip		-1			
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$	Legacy chip		40	200	μV_{rms}	
		New chip		120	200		
Dropout voltage		Legacy chip and new chip		2.0		V	
Bias current		Legacy chip		4.5	6	mA	
		New chip	3.5	4.5	6		
Bias current change	$V_I = 8\text{V to }25\text{V}$, $I_O = 200\text{mA}$	$T_J = \text{full range}$ Legacy chip			0.8	mA	
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$ New chip			0.8		
	$I_O = 5\text{ mA to }350\text{mA}$	$T_J = \text{full range}$ Legacy chip			0.5		
		$T_J = -40^\circ\text{C to }125^\circ\text{C}$ New chip			0.5		
Short-circuit output current	$V_I = 35\text{V}$	Legacy chip		300		mA	
	$V_I = 30\text{V}$	New chip		400			
Peak output current		Legacy chip		700		mA	
		New chip		760			

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.7 Electrical Characteristics: UA78M06C (Legacy Chip Only)

specified at $T_J = 25^\circ\text{C}$, $V_I = 11\text{V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage	$V_I = 8\text{V to }21\text{V}$, and $I_O = 5\text{mA to }350\text{mA}$		5.75	6	6.25	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	5.7		6.3	
Output voltage line regulation	$I_O = 200\text{mA}$, $V_{IN} = 8\text{V to }25\text{V}$			5	100	mV
	$I_O = 200\text{mA}$, $V_{IN} = 9\text{V to }25\text{V}$			1.5	50	
Ripple rejection	$V_I = 8\text{V to }18\text{V}$, $f = 120\text{Hz}$	$I_O = 100\text{mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	59			dB
		$I_O = 300\text{mA}$	59	80		

5.7 Electrical Characteristics: UA78M06C (Legacy Chip Only) (continued)

specified at $T_J = 25^\circ\text{C}$, $V_I = 11\text{V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage load regulation	$I_O = 5\text{mA to } 500\text{mA}$			20	120	mV
	$I_O = 5\text{mA to } 200\text{mA}$			10	60	
Temperature coefficient of output voltage	$I_O = 5\text{mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		-1		mV/ $^\circ\text{C}$
Output noise voltage	$f = 10\ \text{Hz to } 100\ \text{kHz}$,			45		μV_{rms}
Dropout voltage				2.0		V
Bias current			3.5	4.5	6	mA
Bias current change	$V_I = 9\text{V to } 25\text{V}$, $I_O = 200\text{mA}$				0.8	mA
	$I_O = 5\ \text{mA to } 350\text{mA}$		$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		0.5	
Short-circuit output current	$V_I = 35\text{V}$	$V_I = 35\text{V}$			270	mA
Peak output current					700	mA

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.8 Electrical Characteristics: UA78M08C (Legacy Chip Only)

specified at $T_J = 25^\circ\text{C}$, $V_I = 14\text{V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT	
Output voltage	$V_I = 10.5\text{V to } 23\text{V}$, and $I_O = 5\text{mA to } 350\text{mA}$		7.7	8	8.3	V	
	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		7.6		8.4		
Output voltage line regulation	$I_O = 200\text{mA}$, $V_{IN} = 10.5\text{V to } 25\text{V}$				6	mV	
	$I_O = 200\text{mA}$, $V_{IN} = 11\text{V to } 25\text{V}$				2		
Ripple rejection	$V_I = 11\text{V to } 21.5\text{V}$, $f = 120\text{Hz}$		$I_O = 100\text{mA}$, $T_J = 0^\circ\text{C to } 125^\circ\text{C}$		56	dB	
			$I_O = 300\text{mA}$		56		
Output voltage load regulation	$I_O = 5\text{mA to } 500\text{mA}$				25	mV	
	$I_O = 5\text{mA to } 200\text{mA}$				10		
Temperature coefficient of output voltage	$I_O = 5\text{mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$			-1	mV/ $^\circ\text{C}$	
Output noise voltage	$f = 10\ \text{Hz to } 100\ \text{kHz}$,				52	μV_{rms}	
Dropout voltage					2.0	V	
Bias current					4.5	6	mA
Bias current change	$V_I = 9\text{V to } 25\text{V}$, $I_O = 200\text{mA}$		$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		0.8	mA	
	$I_O = 5\ \text{mA to } 350\text{mA}$		$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		0.5		
Short-circuit output current	$V_I = 35\text{V}$				250	mA	
Peak output current					700	mA	

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.9 Electrical Characteristics: UA78M09 (Both Legacy and New Chip)

at specified junction temperature, $V_I = 16\ \text{V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\ \text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage	$V_I = 11.5\text{V to } 24\text{V}$, and $I_O = 5\text{mA to } 350\text{mA}$		8.6	9	9.4	V
	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$		8.5		9.5	
Output voltage line regulation	$I_O = 200\text{mA}$, $V_{IN} = 11.5\text{V to } 26\text{V}$		Legacy chip		6	mV
			and new chip		100	
			Legacy chip		6	
			New chip		30	
	$I_O = 200\text{mA}$, $V_{IN} = 12\text{V to } 26\text{V}$		Legacy chip		2	mV
			New chip		25	

5.9 Electrical Characteristics: UA78M09 (Both Legacy and New Chip) (continued)

at specified junction temperature, $V_I = 16\text{ V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Ripple rejection	$V_I = 13\text{ V to }23\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	Legacy chip	56		dB
			New chip	48		
		$I_O = 300\text{ mA}$	Legacy chip	56	80	
			New chip	48	80	
Output voltage load regulation	$I_O = 5\text{ mA to }500\text{ mA}$	Legacy chip	25	180	mV	
		New chip	25	90		
	$I_O = 5\text{ mA to }200\text{ mA}$	Legacy chip	10	90		
		New chip	10	45		
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$	Legacy chip	58		μV_{rms}	
		New chip	230			
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	Legacy chip and new chip		-1	$\text{mV}/^\circ\text{C}$
Dropout voltage			Legacy chip and new chip		2.0	V
Bias current			Legacy chip and new chip		4.6 6	mA
Bias current change	$V_I = 11.5\text{ V to }26\text{ V}$, $I_O = 200\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	Legacy chip and new chip		0.8	mA
	$I_O = 5\text{ mA to }350\text{ mA}$	$T_J = 0^\circ\text{C to }125^\circ\text{C}$	Legacy chip and new chip		0.5	
Short-circuit output current	$V_I = 35\text{ V}$		Legacy chip		250	mA
	$V_I = 30\text{ V}$		New chip		400	
Peak output current			Legacy chip		700	mA
			New chip		760	

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.10 Electrical Characteristics: UA78M10 (Both Legacy and New Chip)

at specified junction temperature, $V_I = 17\text{ V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage	$V_I = 12.5\text{ V to }25\text{ V}$, and $I_O = 5\text{ mA to }350\text{ mA}$		9.6	10	10.4	V
		$T_J = 0^\circ\text{C to }125^\circ\text{C}$	9.5		10.5	
Output voltage line regulation	$I_O = 200\text{ mA}$, $V_{IN} = 12.5\text{ V to }28\text{ V}$	Legacy chip	7	100	mV	
		New chip	7	35		
	$I_O = 200\text{ mA}$, $V_{IN} = 14\text{ V to }28\text{ V}$	Legacy chip	2	50		
		New chip	2	30		
Ripple rejection	$V_I = 15\text{ V to }25\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to }125^\circ\text{C}$	Legacy chip	59		dB
			New chip	45		
		$I_O = 300\text{ mA}$	Legacy chip	55	80	
			New chip	45	80	
Output voltage load regulation	$I_O = 5\text{ mA to }500\text{ mA}$	Legacy chip	25	200	mV	
		New chip	25	120		
	$I_O = 5\text{ mA to }200\text{ mA}$	Legacy chip	10	100		
		New chip	10	50		
Output noise voltage	$f = 10\text{ Hz to }100\text{ kHz}$	Legacy chip	64		μV_{rms}	
		New chip	255			

5.10 Electrical Characteristics: UA78M10 (Both Legacy and New Chip) (continued)

at specified junction temperature, $V_I = 17\text{ V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$, and $I_O = 350\text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾			MIN	TYP	MAX	UNIT
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip and new chip		-1		mV/°C
Dropout voltage			Legacy chip and new chip		2.0		V
Bias current			Legacy chip and new chip		4.7	6	mA
Bias current change	$V_I = 12.5\text{ V to } 28\text{ V}$, $I_O = 200\text{ mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip and new chip			0.8	mA
	$I_O = 5\text{ mA to } 350\text{ mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip and new chip			0.5	
Short-circuit output current	$V_I = 35\text{ V}$		Legacy chip		245		mA
	$V_I = 30\text{ V}$		New chip		400		
Peak output current			Legacy chip		700		mA
			New chip		760		

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.11 Electrical Characteristics: UA78M12 (Both Legacy and New Chip)

at specified at $T_J = 25^\circ\text{C}$, $V_I = 19\text{ V}$, $C_{IN} = 0.33\ \mu\text{F}$, $C_{OUT} = 0.1\ \mu\text{F}$ and $I_O = 350\text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾			MIN	TYP	MAX	UNIT
Output voltage	$V_I = 14.5\text{ V to } 27\text{ V}$, and $I_O = 5\text{ mA to } 350\text{ mA}$		Legacy chip and new chip	11.5	12	12.5	V
		$T_J = 0^\circ\text{C to } 125^\circ\text{C}$			11.4		
Output voltage line regulation	$I_O = 200\text{ mA}$, $V_{IN} = 14.5\text{ V to } 30\text{ V}$		Legacy chip		8	100	mV
			New chip		8	40	
	$I_O = 200\text{ mA}$, $V_{IN} = 16\text{ V to } 30\text{ V}$		Legacy chip		2	50	
			New chip		2	35	
Ripple rejection	$V_I = 15\text{ V to } 25\text{ V}$, $f = 120\text{ Hz}$	$I_O = 100\text{ mA}$, $T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip		55		dB
			New chip		42		
		$I_O = 300\text{ mA}$	Legacy chip		55	80	
			New chip		42	80	
Output voltage load regulation	$I_O = 5\text{ mA to } 500\text{ mA}$		Legacy chip		25	240	mV
			New chip		25	120	
	$I_O = 5\text{ mA to } 200\text{ mA}$		Legacy chip		10	120	
			New chip		10	60	
Temperature coefficient of output voltage	$I_O = 5\text{ mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip and new chip		-1		mV/°C
Output noise voltage	$f = 10\text{ Hz to } 100\text{ kHz}$		Legacy chip		75		μV_{rms}
			New chip		300		
Dropout voltage			Legacy chip and new chip		2.0		V
Bias current			Legacy chip and new chip		4.8	6	mA
Bias current change	$V_I = 14.5\text{ V to } 30\text{ V}$, $I_O = 200\text{ mA}$	$T_J = 0^\circ\text{C to } 125^\circ\text{C}$	Legacy chip and new chip			0.8	mA
	$I_O = 5\text{ mA to } 350\text{ mA}$		Legacy chip and new chip			0.5	
Short-circuit output current	$V_I = 35\text{ V}$		Legacy chip		240		mA
	$V_I = 30\text{ V}$		New chip		400		

5.11 Electrical Characteristics: UA78M12 (Both Legacy and New Chip) (continued)

at specified at $T_J = 25^\circ\text{C}$, $V_I = 19\text{V}$, $C_{IN} = 0.33\mu\text{F}$, $C_{OUT} = 0.1\mu\text{F}$ and $I_O = 350\text{mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Peak output current		Legacy chip		700		mA
Peak output current		New chip		760		

(1) Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

5.12 Typical Characteristics

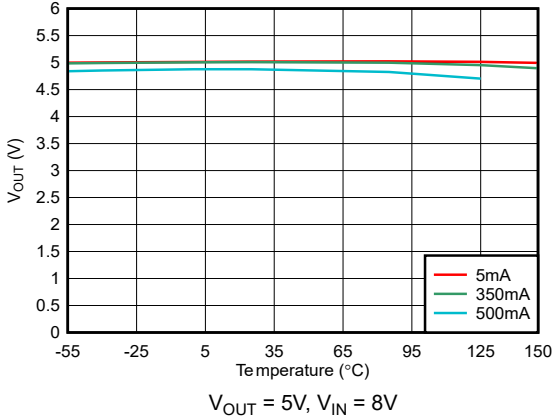


Figure 5-1. Output Voltage vs Temperature (New Chip)

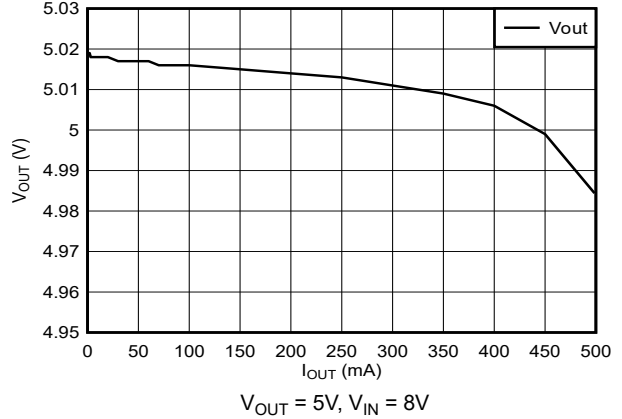


Figure 5-2. Load Regulation at $T_J = 25^\circ\text{C}$ (New Chip)

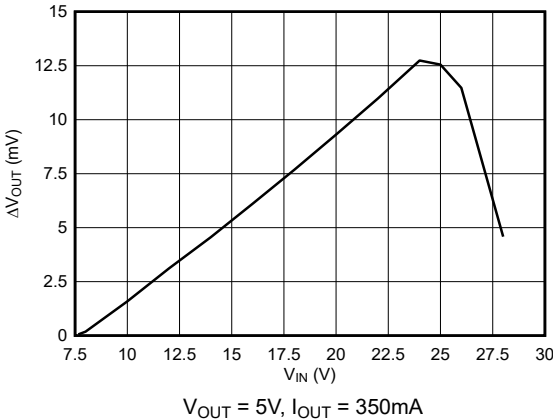


Figure 5-3. Line Regulation at $T_J = 25^\circ\text{C}$ (New Chip)

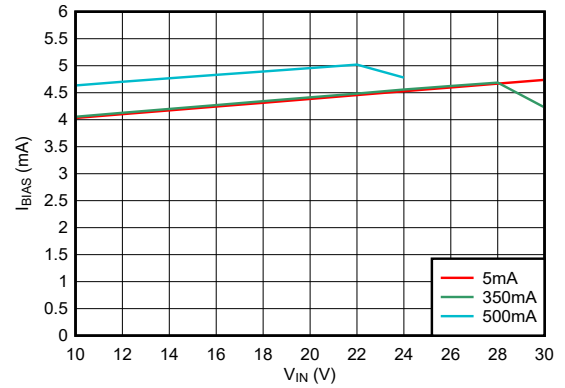


Figure 5-4. Bias Current vs Input Voltage at $T_J = 25^\circ\text{C}$ (New Chip)

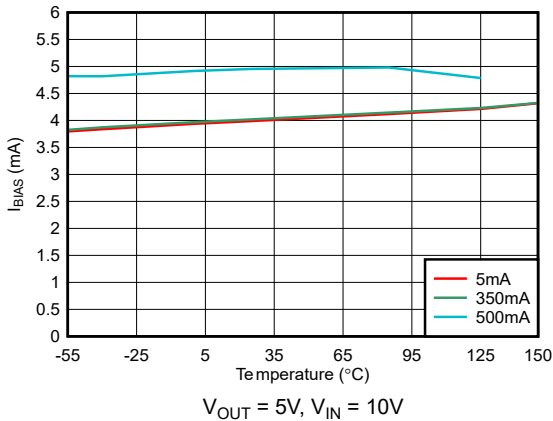


Figure 5-5. Bias Current vs Temperature (New Chip)

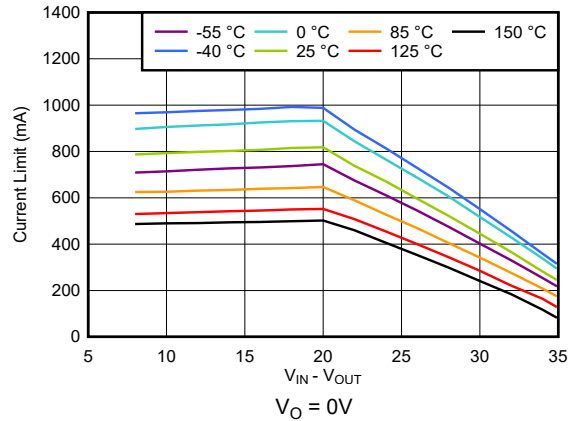


Figure 5-6. I_{CL} vs Input Voltage (New Chip)

5.12 Typical Characteristics (continued)

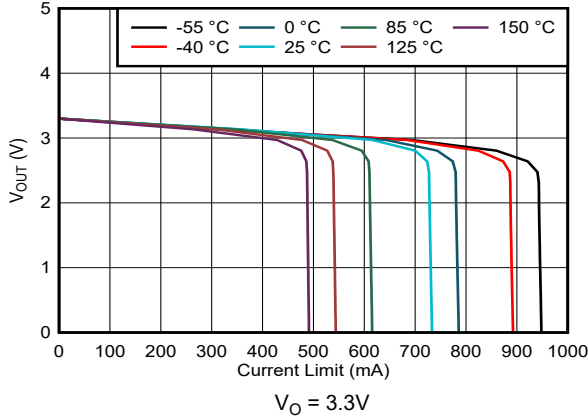


Figure 5-7. Output Voltage vs I_{CL} (New Chip)

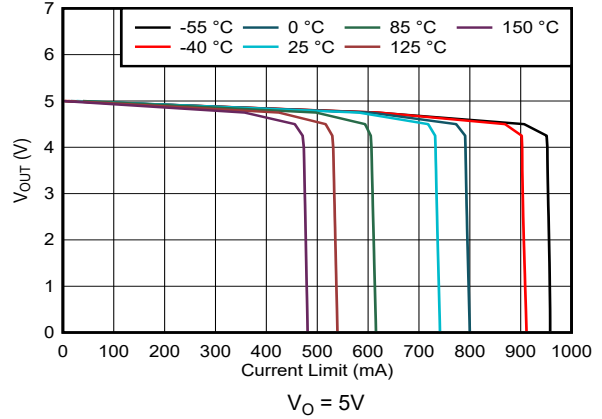


Figure 5-8. Output Voltage vs I_{CL} (New Chip)

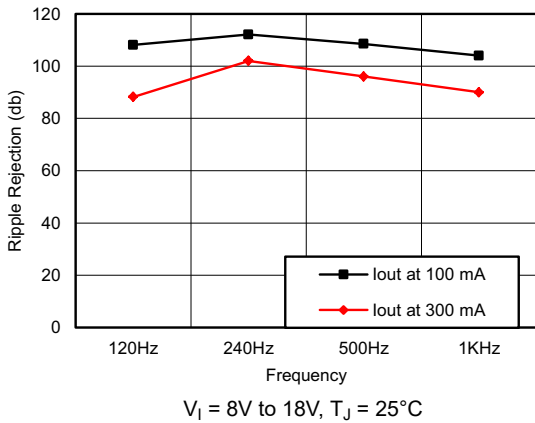


Figure 5-9. PSRR vs Frequency and I_O (Legacy Chip)

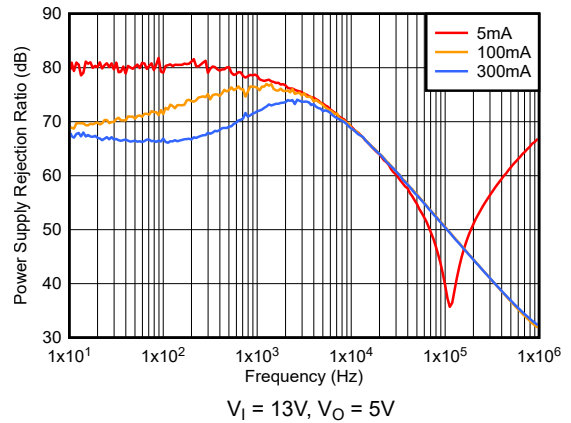
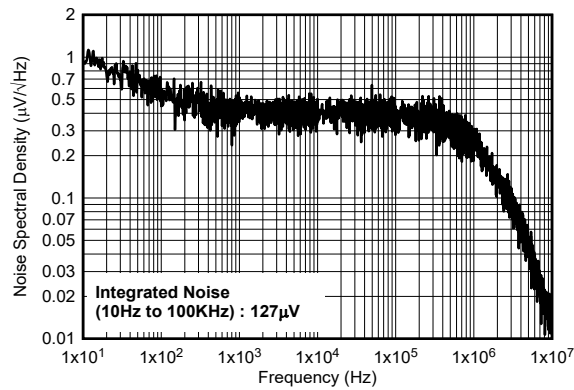


Figure 5-10. PSRR vs Frequency and I_O (New Chip)



$V_{IN} = 10V, V_{OUT} = 5V, I_{OUT} = 100mA, C_{OUT} = 0.1\mu F$

Figure 5-11. Noise vs Frequency (New Chip)

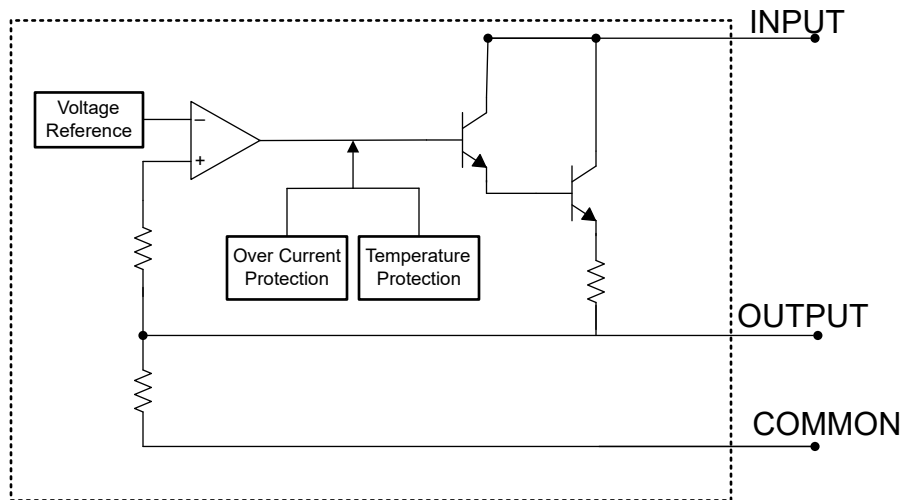
6 Detailed Description

6.1 Overview

The UA78M fixed-voltage, integrated-circuit voltage regulator is designed for a wide range of applications. The UA78M supports a wide range of input voltages and delivers 500mA of load current.

This device features internal current-limiting and thermal shutdown mechanisms. To provide reliable operation across wide V_I ranges, the current-limiting mechanism modulates the load current capacity both by monitoring the V_O level and the difference between the V_I and V_O voltage levels. The operating ambient temperature range of the device is -40°C to $+125^{\circ}\text{C}$ for all variants.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Current Limit

The device has an internal current-limit circuit that protects the regulator during transient high-load current faults or shorting events. In a high-load current fault, the current limit scheme limits the output current to the current limit (I_{CL}). I_{CL} is listed in the *Electrical Characteristics* table.

The output voltage is not regulated when the device is in current limit. When a current-limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in current limit, the pass transistor dissipates power $[(V_I - V_O) \times I_{CL}]$. For more information on current limits, see the [Know Your Limits application note](#).

To achieve a safe operation across a wide range of Input voltage, the UA78M also has a built-in protection mechanism with current limit. The protection mechanism decreases the current limit as input-to-output voltage increases and keeps the power transistor inside a safe operating region for all values of input-to-output voltage. This protection is designed to provide some output current at all values of input-to-output voltage limits defined in the [Recommended Operating Conditions](#) table. [Figure 6-1](#) shows the behavior of the current limit variation.

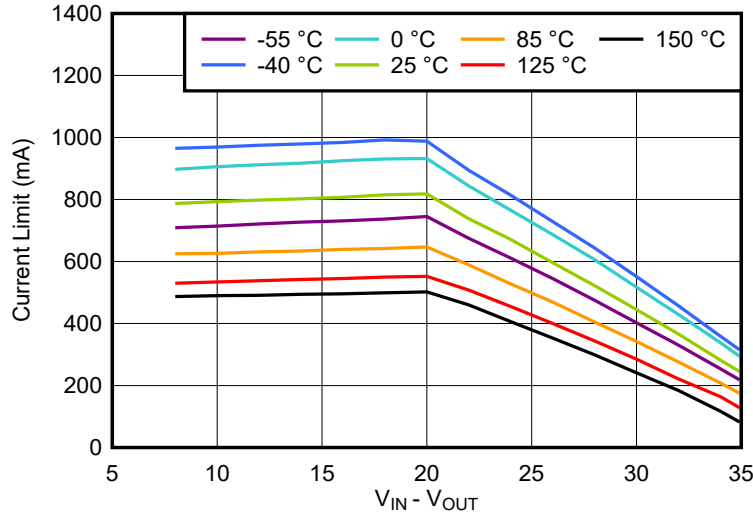


Figure 6-1. Current-Limit vs $V_{\text{Head-room}}$ Behavior (New Chip)

6.3.2 Dropout Voltage (V_{DO})

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage ($V_I - V_O$) at the rated output current (I_{RATED}), where the pass transistor is fully on. I_{RATED} is the maximum I_O listed in the [Recommended Operating Conditions](#) table. In dropout operation, the pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the value required to maintain output regulation, then the output voltage falls as well.

6.3.3 Thermal Shutdown

The device contains a thermal shutdown protection circuit to disable the device when the junction temperature (T_J) of the pass transistor rises to $T_{SD(\text{shutdown})}$ (typical). Thermal shutdown hysteresis makes sure that the device resets (turns on) when the temperature falls to $T_{SD(\text{reset})}$ (typical).

The thermal time-constant of the semiconductor die is fairly short, thus the device can cycle on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during start-up can be high from large $V_I - V_O$ voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before start-up completes.

For reliable operation, limit the junction temperature to the maximum listed in the [Recommended Operating Conditions](#) table. Operation above this maximum temperature causes the device to exceed operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overall conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

6.4 Device Functional Modes

Table 6-1 provides a quick comparison between the normal and dropout modes of operation.

Table 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER	
	V_I	I_O
Normal	$V_I > V_{OUT(nom)} + V_{DO}$	$I_O < I_{CL}$
Dropout	$V_I < V_{OUT(nom)} + V_{DO}$	$I_O < I_{CL}$

6.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_O < I_{CL}$)
- The device junction temperature is greater than -40°C and less than $+125^{\circ}\text{C}$

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_I < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The UA78M is designed for use as a linear regulator with only a few external components needed. Use the UA78M to clean power-supply noise by attenuating ripple on the input signal.

7.2 Typical Application

The UA78M is typically used as a fixed-output linear regulator, sourcing current up to 500mA into a load.

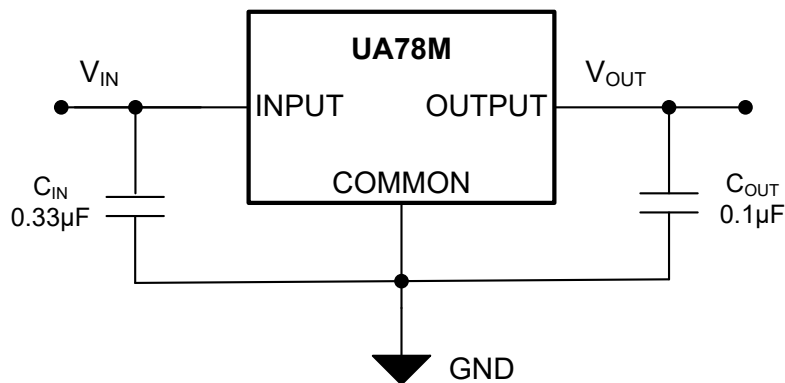


Figure 7-1. Fixed-Output Regulator

7.2.1 Design Requirements

Tie the COMMON pin to ground to set the OUTPUT pin to the desired fixed output voltage.

Although not required, a 0.33µF bypass capacitor is recommended on the input, and a 0.1µF bypass capacitor is recommended on the output.

7.2.2 Detailed Design Procedure

7.2.2.1 Input and Output Capacitor Requirements

Although the input and output capacitors are not required for stability, good analog design practice is to connect a capacitor from INPUT to COMMON and from OUTPUT to COMMON. The input capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. Use an input capacitor if the source impedance is more than 0.5Ω. A higher value capacitor can be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved by using a large output capacitor. Use an output capacitor within the range specified in the [Recommended Operating Conditions](#) table for stability.

7.2.2.2 Power Dissipation (P_D)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. Make sure the PCB area around the regulator has few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. The following equation calculates power dissipation (P_D).

$$P_D = (V_I - V_O) \times I_O \quad (1)$$

Note

Power dissipation is minimized, and therefore greater efficiency be achieved, by correct selection of the system voltage rails. For the lowest power dissipation, use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (2)$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the [Thermal Information](#) table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance. As mentioned in the [An empirical analysis of the impact of board layout on LDO thermal performance application note](#), $R_{\theta JA}$ is improved by 35% to 55% compared to the [Thermal Information](#) table value with the PCB board layout optimization.

7.2.2.3 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the linear regulator when in circuit on a typical PCB board application. These metrics are not thermal resistance parameters and instead offer a practical and relative way to estimate junction temperature. These psi metrics are determined to be significantly independent of the copper area available for heat-spreading. The [Thermal Information](#) table lists the primary thermal metrics, which are the junction-to-top characterization parameter (ψ_{JT}) and junction-to-board characterization parameter (ψ_{JB}). These parameters provide two methods for calculating the junction temperature (T_J), as described in the following equations. Use the junction-to-top characterization parameter (ψ_{JT}) with the temperature at the center-top of device package (T_T) to calculate the junction temperature. Use the junction-to-board characterization parameter (ψ_{JB}) with the PCB surface temperature 1mm from the device package (T_B) to calculate the junction temperature.

$$T_J = T_T + \psi_{JT} \times P_D \quad (3)$$

where:

- P_D is the dissipated power
- T_T is the temperature at the center-top of the device package

$$T_J = T_B + \psi_{JB} \times P_D \quad (4)$$

where:

- T_B is the PCB surface temperature measured 1mm from the device package and centered on the package edge

For detailed information on the thermal metrics and how to use them, see the [Semiconductor and IC Package Thermal Metrics application note](#).

7.2.2.4 External Capacitor Requirements

The UA78M is designed to be stable without any external component. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but use good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the [Recommended Operating Conditions](#) table account for an effective capacitance of approximately 50% of the nominal value.

7.2.2.5 Overload Recovery

As the input voltage rises when power is first turned on, the output follows the input, allowing the regulator to start up into very heavy loads. The input-to-output voltage differential is small during start up when the input voltage is rising, allowing the regulator to supply large output currents. With a high input voltage, a problem occurs where removing an output short does not allow the output voltage to recover. Other regulators also exhibit this phenomenon, so the behavior is not unique to the UA78M.

The problem occurs with a heavy output load when the input voltage is high and the output voltage is low. Common situations occur immediately when removing a short circuit after the input voltage is already turned on. The load line for such a load has the possibility to intersect the output current curve at two points. If this condition happens, there are two stable output operating points for the regulator. With this double intersection, the input power supply is potentially cycled down to zero and brought up again to make the output recover to the desired voltage operating point.

7.2.2.6 Reverse Current

Excessive reverse current can damage this device. Reverse current flows through the emitter-base junction of the pass transistor instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device.

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_O \leq V_I + 7V$. These conditions are:

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, use external protection to protect the device. Reverse current is not limited in the device, so external limiting is required if extended reverse voltage operation is anticipated. Limit reverse current to 5% or less of the rated output current of the device in the event this current cannot be avoided.

Figure 7-2 shows one approach for protecting the device.

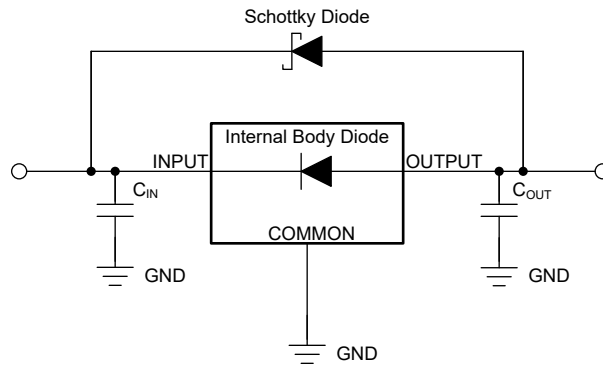


Figure 7-2. Example Circuit for Reverse Current Protection Using a Schottky Diode

7.2.2.7 Polarity Reversal Protection

In many applications, a voltage regulator powers a load that is not connected to ground, but instead, is connected to a voltage source of the opposite polarity (for example, operational amplifiers, level-shifting circuits, and so on). During start-up and short-circuit events, this connection can lead to polarity reversal of the regulator output and can damage the internal components of the regulator.

To avoid polarity reversal on the regulator output, use external protection to protect the device.

Figure 7-3 shows one approach for protecting the device.

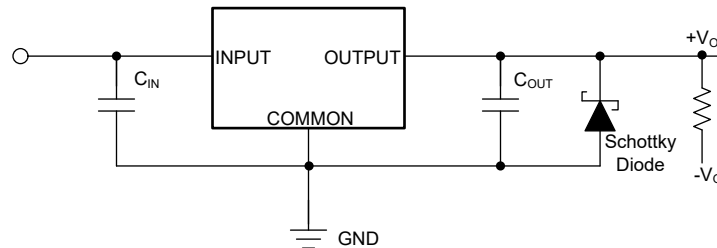


Figure 7-3. Example Circuit for Polarity Reversal Protection Using a Schottky Diode

7.2.3 Application Curves

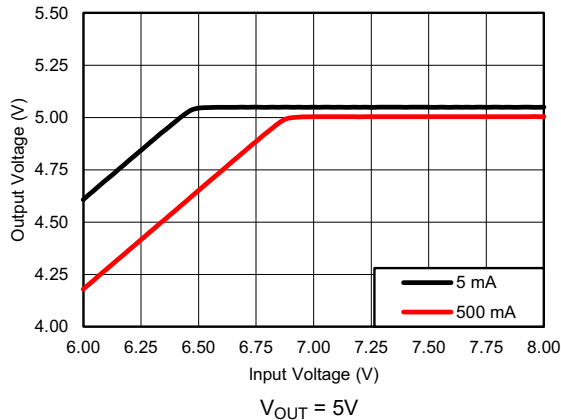


Figure 7-4. V_{IN} vs V_{OUT} at $T_J = 25^\circ\text{C}$ (Legacy Chip)

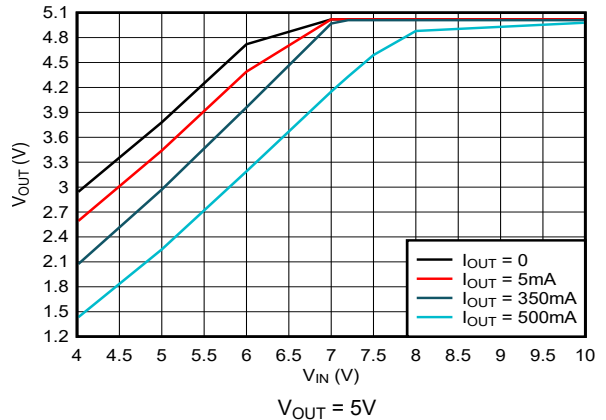


Figure 7-5. V_{IN} vs V_{OUT} at $T_J = 25^\circ\text{C}$ (New Chip)

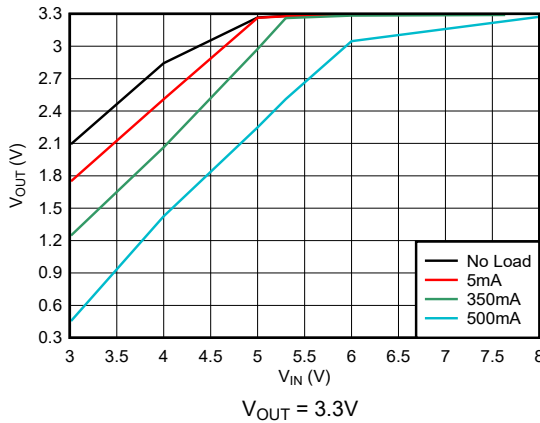
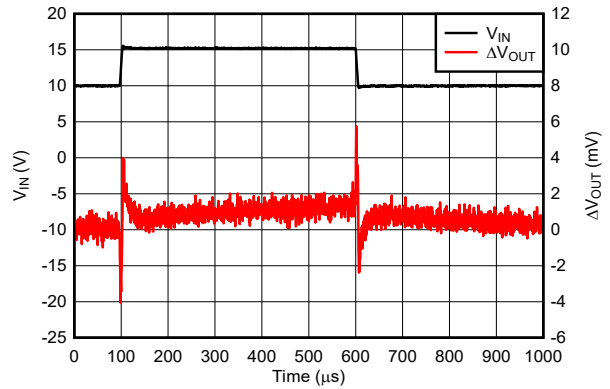
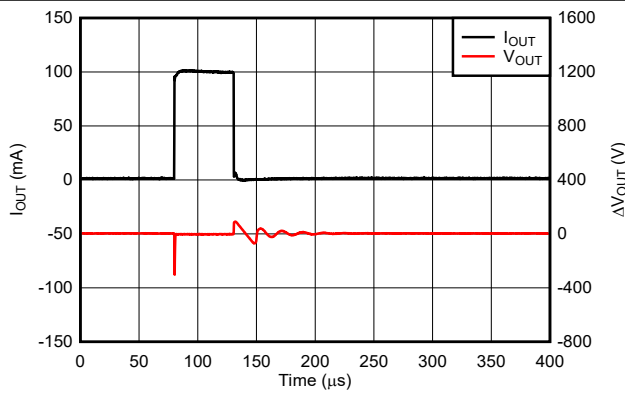


Figure 7-6. V_{IN} vs V_{OUT} at $T_J = 25^\circ\text{C}$ (New Chip)



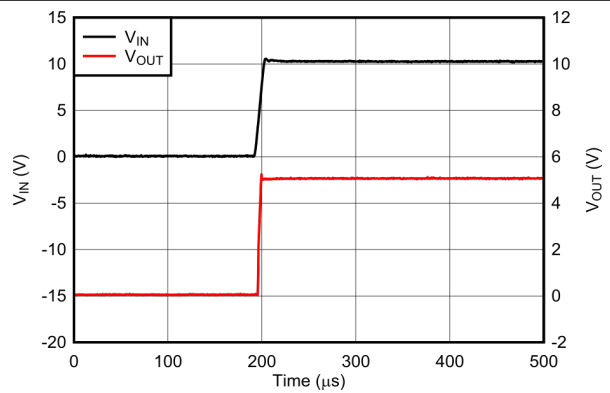
$V_O = 5\text{V}$, $dV_{IN}/dt = 1\text{V}/\mu\text{s}$, $I_{OUT} = 350\text{mA}$, $C_{OUT} = 0.1\mu\text{F}$

Figure 7-7. Line Transient Behavior (New Chip)



$V_{IN} = 10\text{V}$, $V_{OUT} = 5\text{V}$, $I_{OUT} = 1\text{mA}$ to 100mA , $dI/dt = 1\text{A}/\mu\text{s}$, $C_{OUT} = 0.1\mu\text{F}$

Figure 7-8. Load Transient Behavior (New Chip)



$V_{IN} = 0\text{V}$ to 10V , $V_{OUT} = 5\text{V}$, $I_{OUT} = 100\text{mA}$, $dV_{IN}/dt = 1\text{V}/\mu\text{s}$, $C_{OUT} = 0.1\mu\text{F}$

Figure 7-9. Start-Up (New Chip)

7.3 System Examples

7.3.1 Positive Regulator in Negative Configuration

Figure 7-10 shows the UA78M as a positive regulator used in a negative configuration. Make sure V_I floats in this configuration.

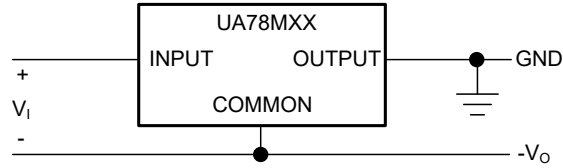


Figure 7-10. Positive Regulator in Negative Configuration

7.3.2 Current Limiter Circuit

Figure 7-11 shows an example of using the UA78M as a current limiter. The output current limit is set by Equation 5,

$$I_O = \left(\frac{V_O}{R1} \right) + I_O \text{ Bias Current} \quad (5)$$

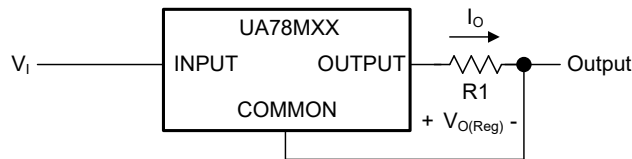


Figure 7-11. Current Limiter Example

7.4 Power Supply Recommendations

See the [Recommended Operating Conditions](#) for the recommended power supply voltages for each variation of the UA78M. Different orderable part numbers are able to tolerate different levels of voltage. Also, place a decoupling capacitor on the output to limit noise on the input.

7.5 Layout

7.5.1 Layout Guidelines

Keep trace widths large enough to eliminate problematic $I \times R$ voltage drops at the input and output pins. Place bypass capacitors as close to the UA78M as possible. Additional copper and vias connected to ground facilitate additional thermal dissipation, preventing the device from reaching thermal overload.

7.5.2 Layout Example

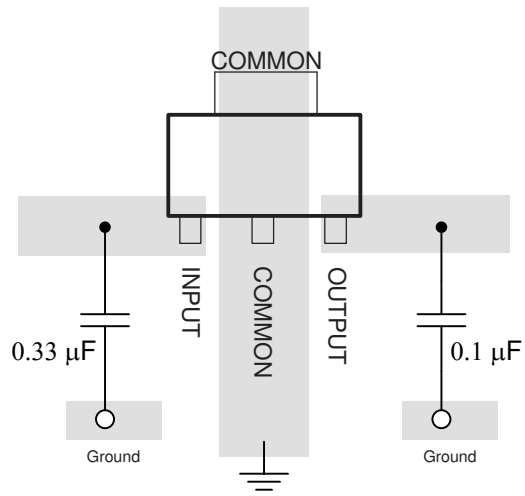


Figure 7-12. Layout Diagram

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

8.1.1.1 Evaluation Module

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the UA78L. The [UA78MEVM](#) (and [related user guide](#)) can be requested at the Texas Instruments website through the product folders or purchased directly from the [TI eStore](#).

8.1.2 Device Nomenclature

Table 8-1. Device Nomenclature

PRODUCT ⁽¹⁾	V _{OUT}
UA78Mxxyyyz	<p>xx is the nominal output voltage (for example, 05 = 5.0V, 15 = 15.0V).</p> <p>yyy is the package designator.</p> <p>z is the package quantity.</p> <p>Devices can ship with the legacy chip (CSO: SFB) or the new chip (CSO: RFB). The reel packaging label provides CSO information to distinguish which chip is being used. Device performance for new and legacy chips is denoted throughout the data sheet.</p>

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](#).

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision U (May 2024) to Revision V (February 2025)	Page
• Deleted 35V from document title.....	1
• Changed <i>Features</i> section: Changed 35V to 30V in <i>Input voltage range</i> bullet, added <i>Absolute maximum input voltage</i> bullet, and deleted <i>Packages</i> bullet.....	1
• Changed <i>Description</i> section.....	1
• Added information of new chip for 9V voltage option.....	7
• Added information of new chip for 10V voltage option.....	8
• Added information of new chip for 12V voltage option.....	9

Changes from Revision T (January 2015) to Revision U (May 2024)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Changed entire document to align with current family format.....	1
• Added M3 devices to document.....	1
• Changed pin names from <i>IN</i> , <i>GND</i> , and <i>OUT</i> to <i>INPUT</i> , <i>COMMON</i> , and <i>OUTPUT</i> throughout document for consistency.....	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN78MCD CYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05C DCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05C DCY G3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05C DCY R	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05C DCY R G3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C5	Samples
UA78M05C KCS	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M05C	Samples
UA78M05C KCS E3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M05C	Samples
UA78M05C K VUR G3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M05C	Samples
UA78M05I DCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(C5, J5)	Samples
UA78M05I DCY G3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(C5, J5)	Samples
UA78M05I DCY R	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(C5, J5)	Samples
UA78M05I DCY R G3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(C5, J5)	Samples
UA78M05I KCS	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	-40 to 125	UA78M05I	Samples
UA78M05I KCS E3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	-40 to 125	UA78M05I	Samples
UA78M05I K VUR G3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	78M05I	Samples
UA78M06C K VUR G3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M06C	Samples
UA78M08C DCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08C DCY G3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08C DCY R	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08C DCY R G3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08C KCS	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M08C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
UA78M08CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M08C	Samples
UA78M08CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M08C	Samples
UA78M09CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M09C	Samples
UA78M10CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M10C	Samples
UA78M12CKCS	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M12C	Samples
UA78M12CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M12C	Samples
UA78M12CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M12C	Samples
UA78M33CDCY	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYG3	ACTIVE	SOT-223	DCY	4	80	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYR	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	RoHS & Green	SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CKCS	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M33C	Samples
UA78M33CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	UA78M33C	Samples
UA78M33CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	78M33C	Samples
UA78M33IKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	-40 to 125	78M33I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

- (3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF UA78M :

- Automotive : [UA78M-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M06CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M08CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M08CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M09CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M12CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M33CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2

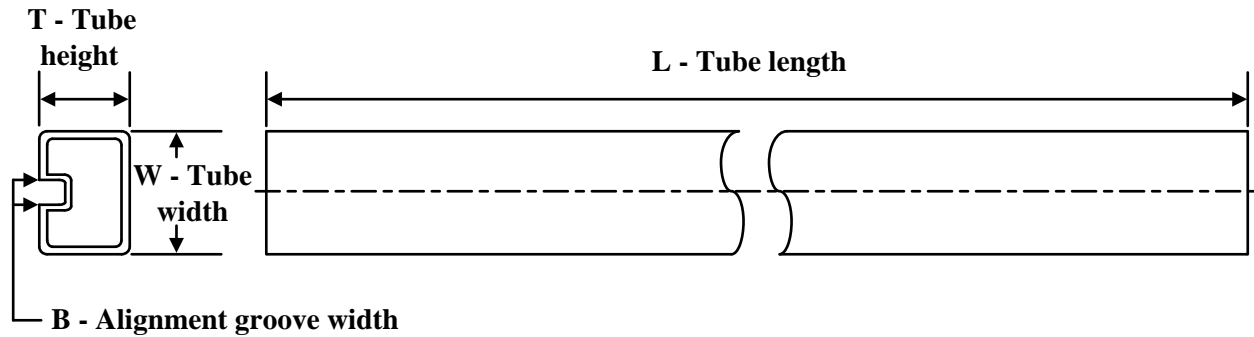
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M331KVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M331KVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

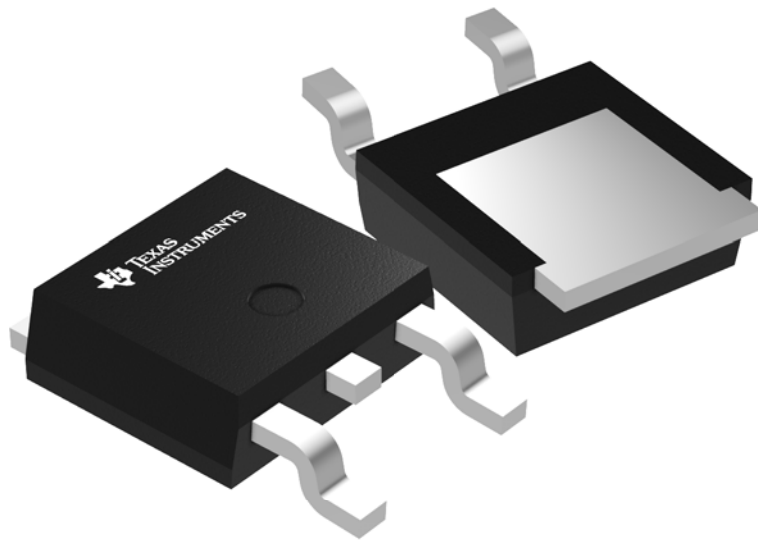
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA78M05CDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05IDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05IDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M05IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M06CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M08CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M08CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M09CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M10CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M10CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M12CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M33CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M33IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
UA78M05CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05IDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05IDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M05IKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05IKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05IKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M05IKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M08CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M08CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M08CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M08CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M08CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M08CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M12CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M12CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M12CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M12CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CDCY	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M33CDCYG3	DCY	SOT-223	4	80	559	8.6	500	3.6
UA78M33CDCYR	DCY	SOT-223	4	2500	559	8.6	500	3.6
UA78M33CDCYRG3	DCY	SOT-223	4	2500	559	8.6	500	3.6
UA78M33CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CKCS	KCS	TO-220	3	50	532	34.1	700	9.6
UA78M33CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
UA78M33CKCSE3	KCS	TO-220	3	50	532	34.1	700	9.6



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

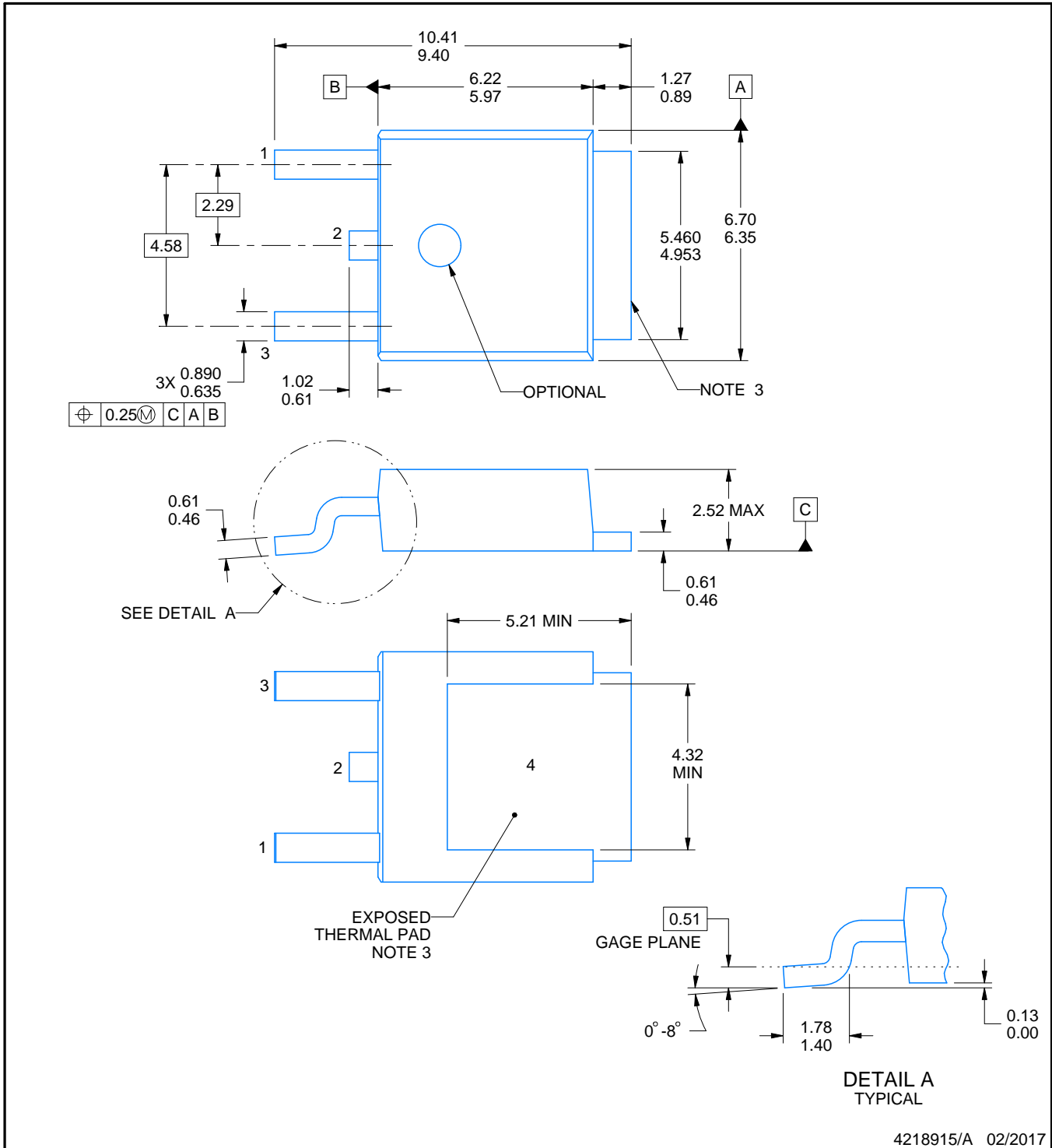


PACKAGE OUTLINE

KVVU0003A

TO-252 - 2.52 mm max height

TO-252



4218915/A 02/2017

NOTES:

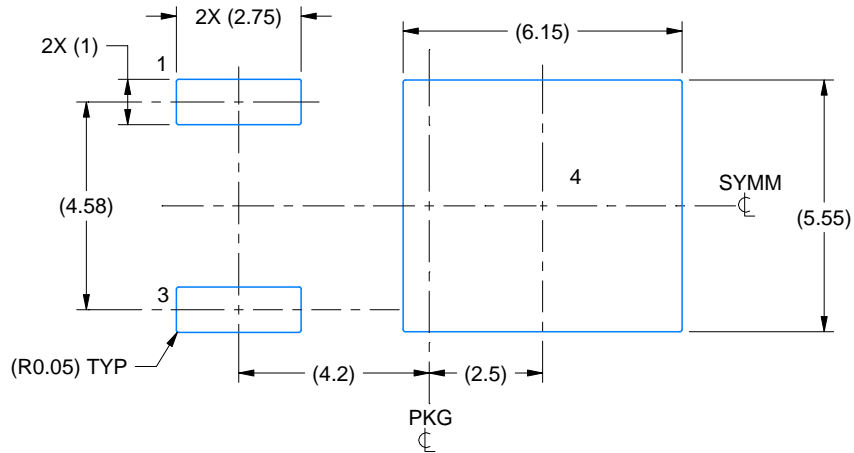
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Shape may vary per different assembly sites.
4. Reference JEDEC registration TO-252.

EXAMPLE BOARD LAYOUT

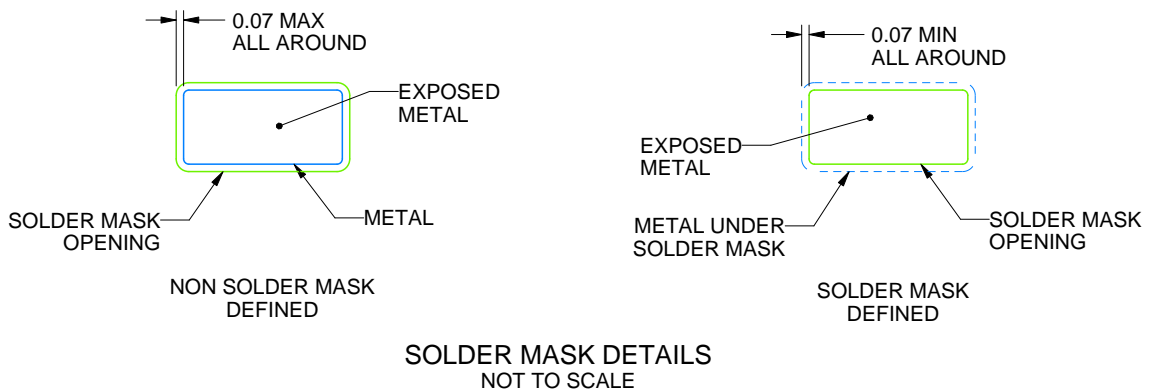
KVU0003A

TO-252 - 2.52 mm max height

TO-252



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:6X



SOLDER MASK DETAILS
NOT TO SCALE

4218915/A 02/2017

NOTES: (continued)

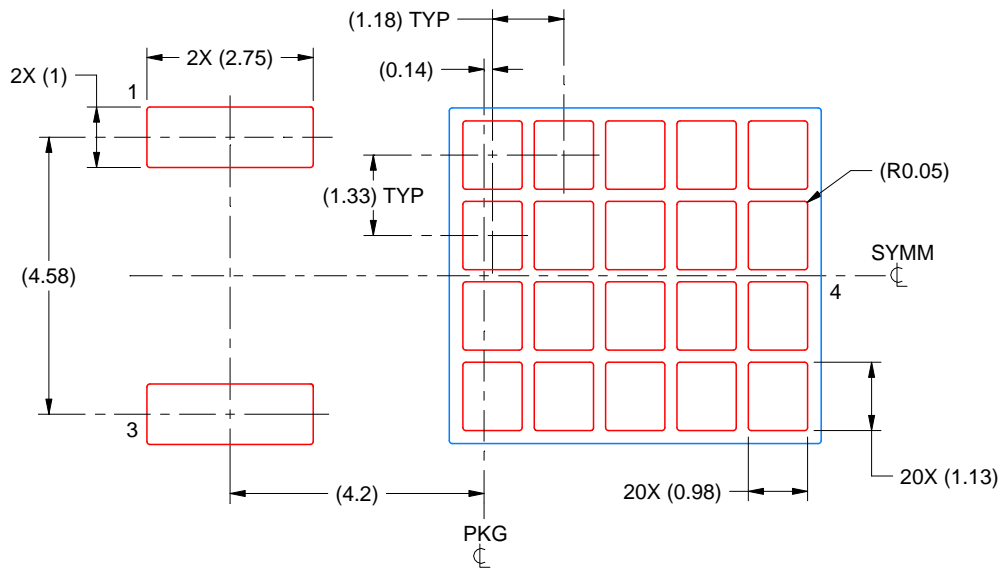
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

KVU0003A

TO-252 - 2.52 mm max height

TO-252



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
65% PRINTED SOLDER COVERAGE BY AREA
SCALE:8X

4218915/A 02/2017

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DCY (R-PDSO-G4)

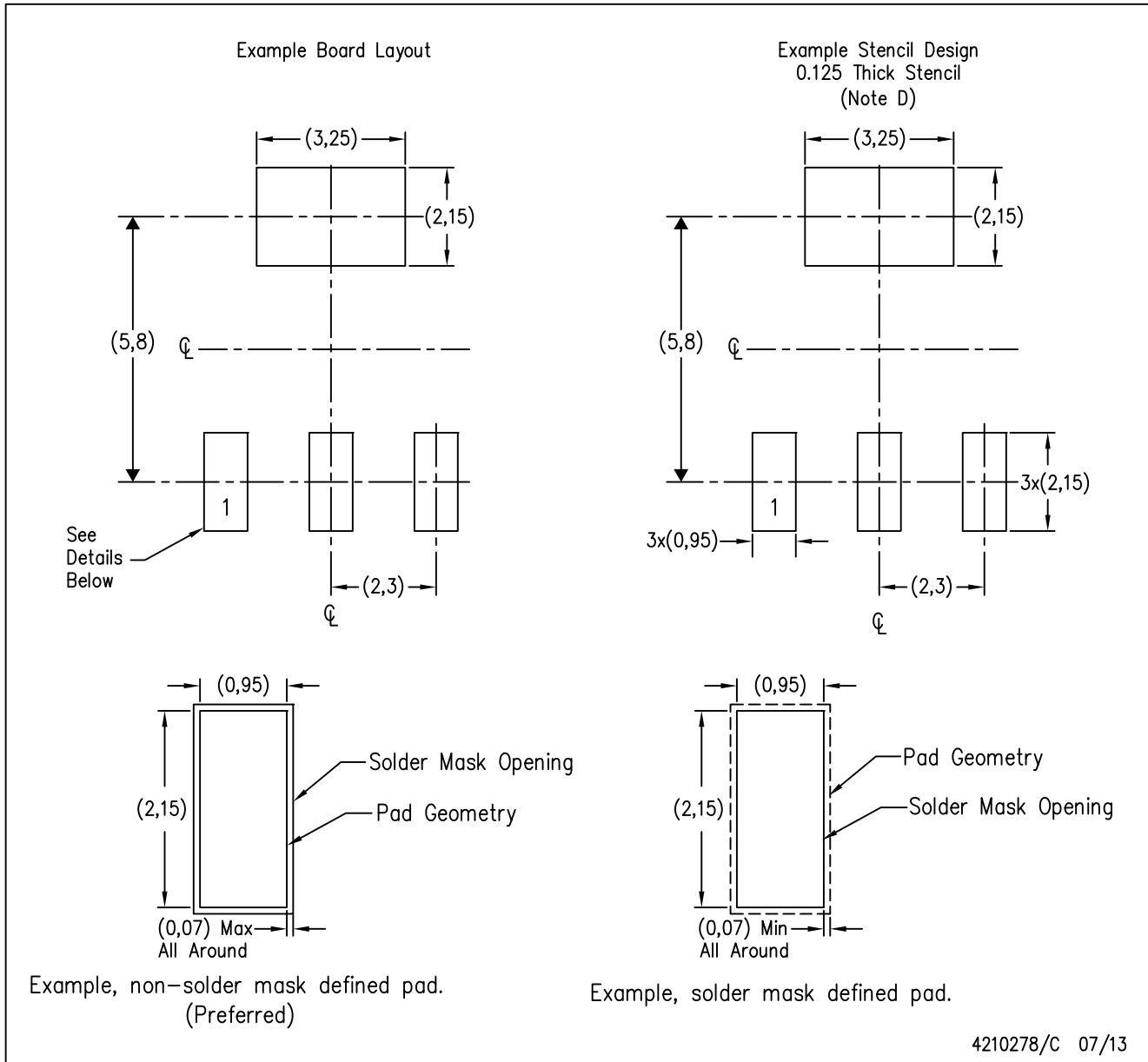
PLASTIC SMALL-OUTLINE



- NOTES: A. All linear dimensions are in millimeters (inches).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion.
 D. Falls within JEDEC TO-261 Variation AA.

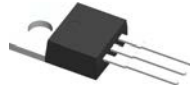
DCY (R-PDSO-G4)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil recommendations. Refer to IPC 7525 for stencil design considerations.

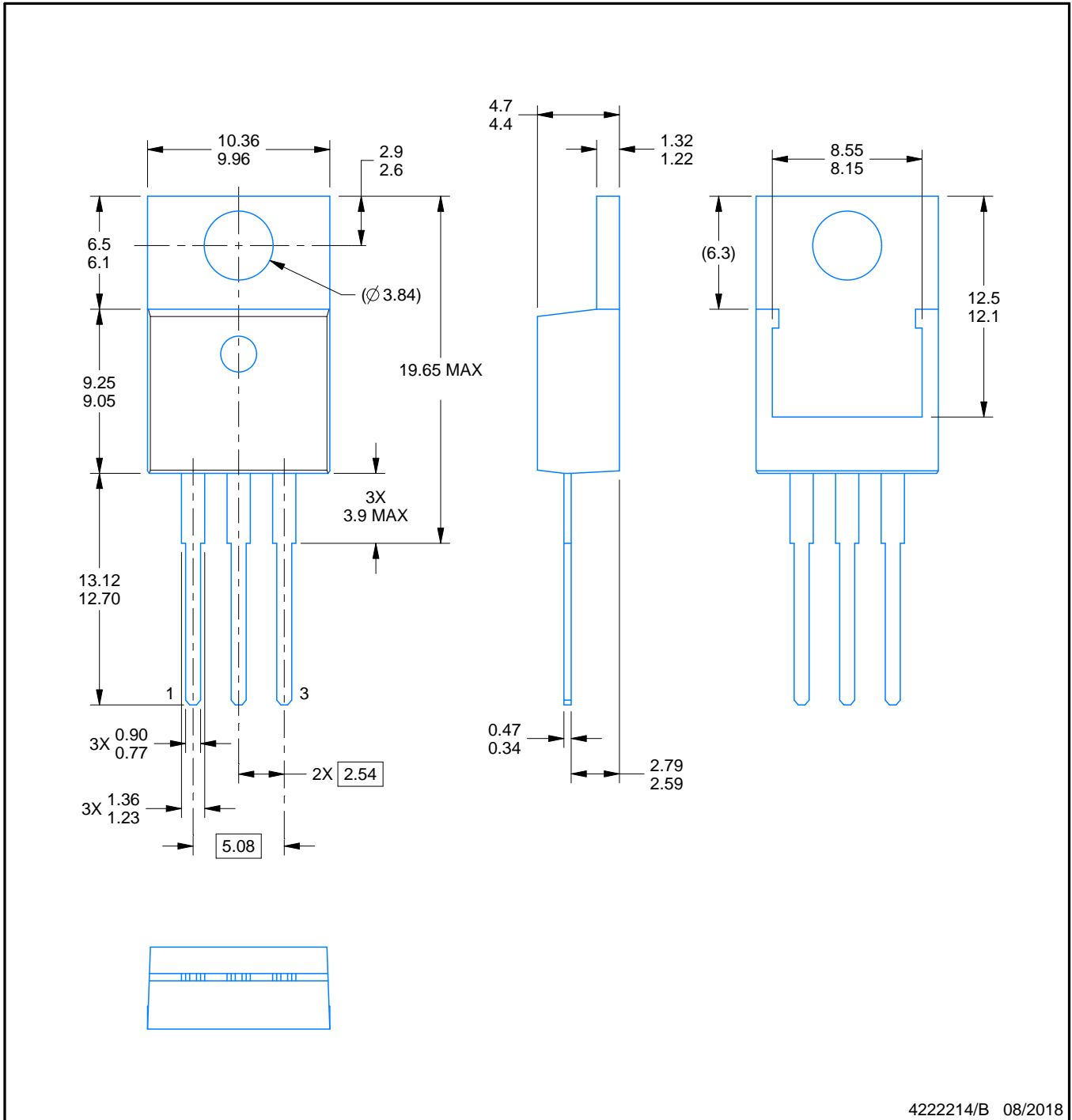
KCS0003B



PACKAGE OUTLINE

TO-220 - 19.65 mm max height

TO-220



4222214/B 08/2018

NOTES:

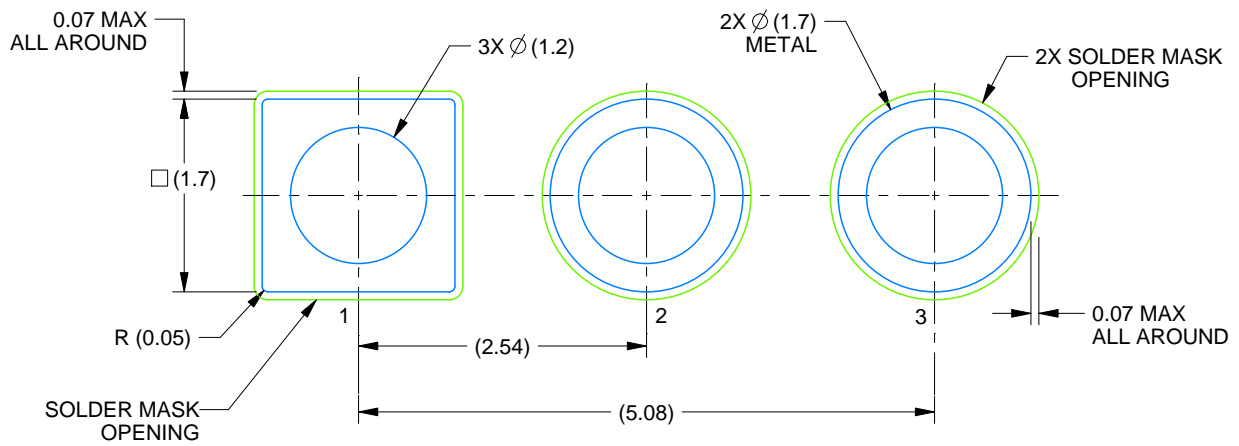
1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-220.

EXAMPLE BOARD LAYOUT

KCS0003B

TO-220 - 19.65 mm max height

TO-220



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE:15X

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